

MOS FIELD EFFECT TRANSISTOR **2SK3112**

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3112 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter, actuator driver.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3112	TO-220AB
2SK3112-S	TO-262
2SK3112-ZJ	TO-263(MP-25ZJ)

- FEATURES
- Gate voltage rating ±30 V
- Low on-state resistance $R_{\text{DS(on)}} = 110 \text{ m}\Omega \text{ MAX. (V}_{\text{GS}} = 10 \text{ V, I}_{\text{D}} = 13 \text{ A})$
- Low input capacitance C_{iss} = 1600 pF TYP. (V_{DS} = 10 V, V_{GS} = 0 V)
- Avalanche capability rated
- Built-in gate protection diode
- Surface mount device available

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage ($V_{GS} = 0 V$)	VDSS	200	V
Gate to Source Voltage ($V_{DS} = 0 V$)	V _{GSS}	±30	V
Drain Current (DC) (Tc = 25°C)	D(DC)	±25	А
Drain Current (pulse) Note1	D(pulse)	±75	А
Total Power Dissipation ($T_c = 25^{\circ}C$)	\mathbf{P}_{T1}	100	W
Total Power Dissipation ($T_A = 25^{\circ}C$)	P_{T2}	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	As	25	А
Single Avalanche Energy Note2	Eas	250	mJ

Notes 1. PW \leq 10 $\mu s,$ Duty Cycle \leq 1%

2. Starting $T_{ch} = 25^{\circ}C$, $V_{DD} = 100$ V, $R_G = 25 \Omega$, $V_{GS} = 20$ V \rightarrow 0 V

(TO-220AB)



(TO-262)



(TO-263)



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ELECTRICAL CHARACTERISTICS (TA = 25°C)

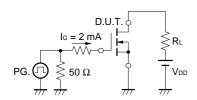
Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	IDSS	Vds = 200 V, Vgs = 0 V			100	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	VGS(off)	Vps = 10 V, Ip = 1 mA	2.5		4.5	V
Forward Transfer Admittance	yfs	Vds = 10 V, Id = 13 A	6.0			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, Id = 13 A		76	110	mΩ
Input Capacitance	Ciss	Vps = 10 V		1600		pF
Output Capacitance	Coss	Vgs = 0 V		430		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		280		pF
Turn-on Delay Time	td(on)	Vdd = 100 V , Id = 13 A		35		ns
Rise Time	tr	Vgs = 10 V		140		ns
Turn-off Delay Time	td(off)	Rg = 10 Ω		110		ns
Fall Time	tr			70		ns
Total Gate Charge	QG	Vdd = 160 V		60		nC
Gate to Source Charge	Q _{GS}	Vgs = 10 V		11		nC
Gate to Drain Charge	Qgd	ID = 25 A		40		nC
Body Diode Forward Voltage	VF(S-D)	IF = 25 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 25 A, VGS = 0 V		300		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/µs		1.8		μC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

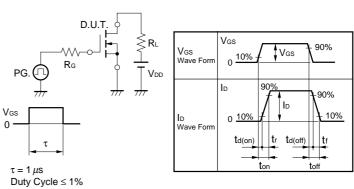
PG. $V_{GS} = 20 \text{ V} \rightarrow 0 \text{ V}$ V_{DD} V_{DD}

Starting Tch

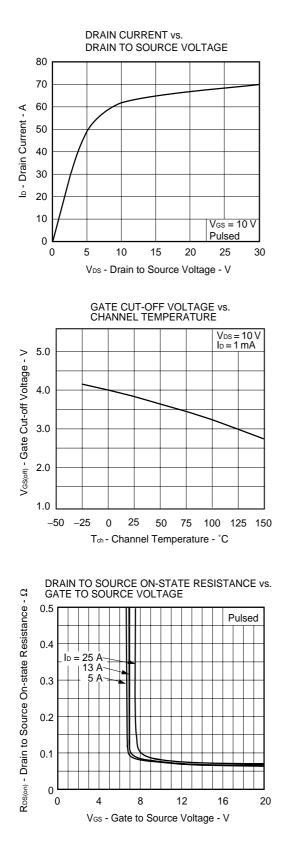
TEST CIRCUIT 3 GATE CHARGE

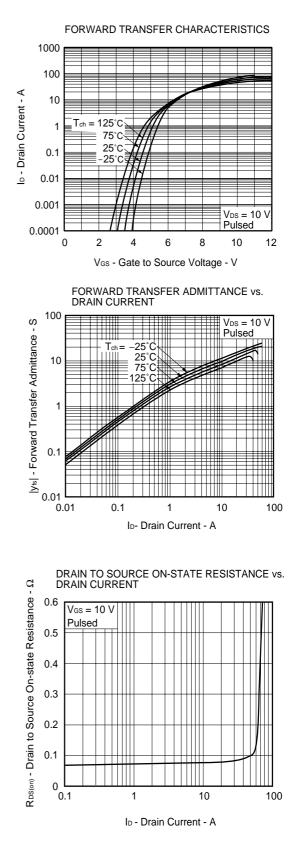


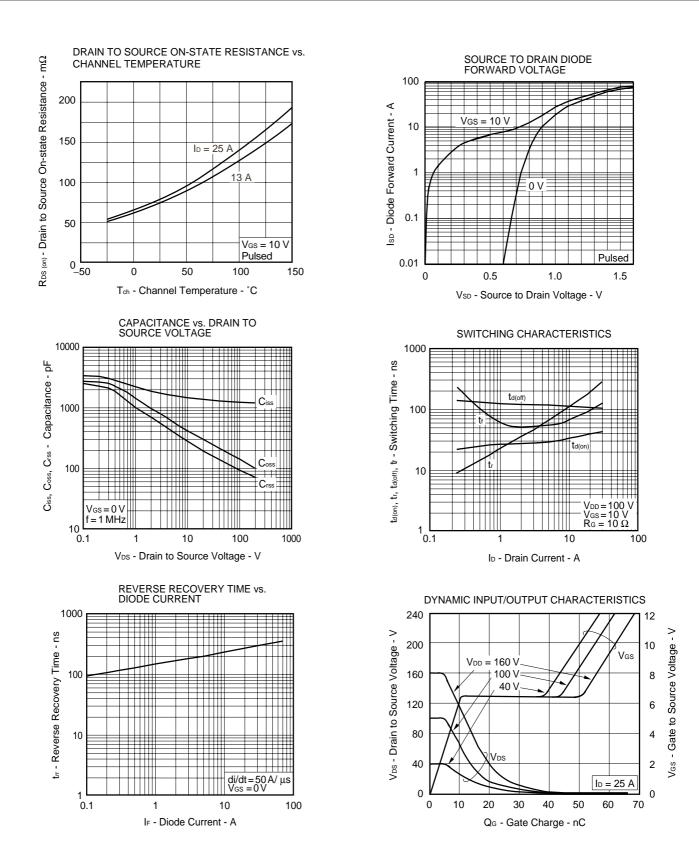
TEST CIRCUIT 2 SWITCHING TIME

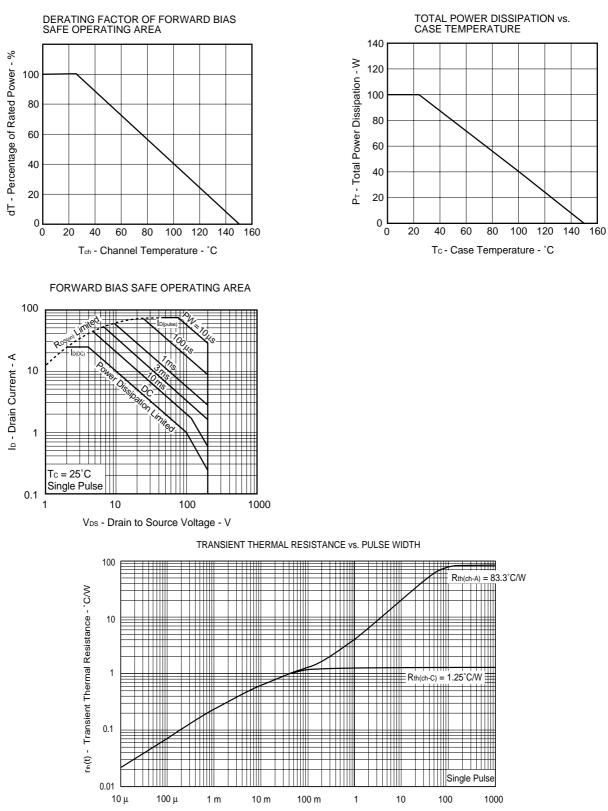


TYPICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

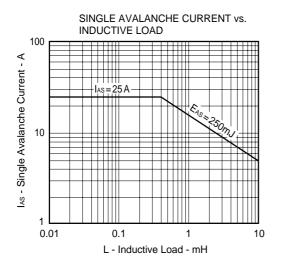


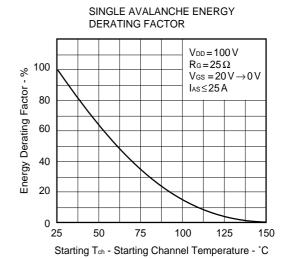






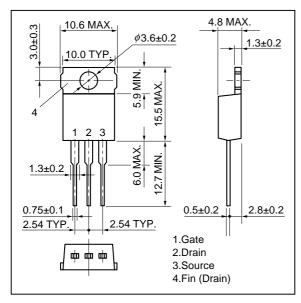
PW - Pulse Width - sec



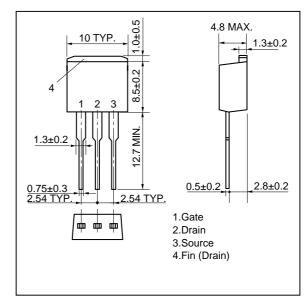


PACKAGE DRAWINGS (Unit : mm)

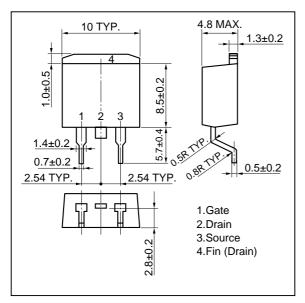
1)TO-220AB (MP-25)



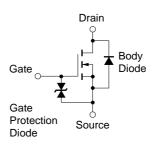
2)TO-262



3)TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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